



**ZXTN25060BZ** 

#### 60V NPN MEDIUM POWER TRANSISTOR IN SOT89

#### **Features**

- BV<sub>CEO</sub> > 60V
- I<sub>C</sub> = 5A Continuous Collector Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 70mV @ 1A</li>
- R<sub>sat</sub> = 48mΩ for a Low Equivalent On-Resistance
- P<sub>D</sub> = 2.4W Power Dissipation
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

https://www.diodes.com/guality/product-definitions/

## **Mechanical Data**

- Package: SOT89
- Package Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.055 grams (Approximate)

#### **Applications**

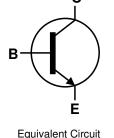
- Emergency lighting circuits
- Motor driving (including DC fans)
- Solenoid, relay, and actuator drivers

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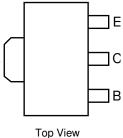
- DC-DC modules
- Backlight inverters
- Power switches
- MOSFET gate drivers







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Pin-Out

#### Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN25060BZTA	Standard	1C7	7	12mm	1,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

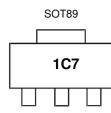
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**

Notes:



1C7= Product Type Marking Code



### Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage (Forward Blocking)	V <sub>CEX</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Collector Voltage (Reverse Blocking)	V <sub>ECO</sub>	6	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ι <sub>C</sub>	5	A
Peak Pulse Collector Current (Single Pulse)	I <sub>CM</sub>	10	A
Base Current	IB	1	Α

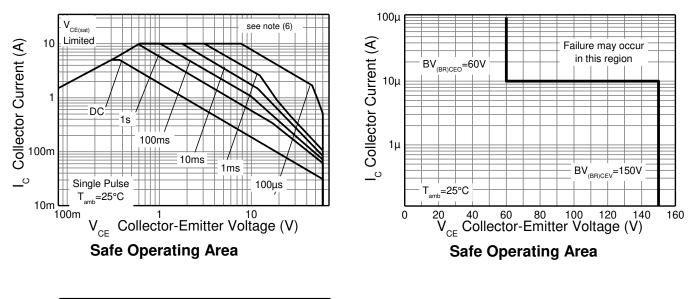
### Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

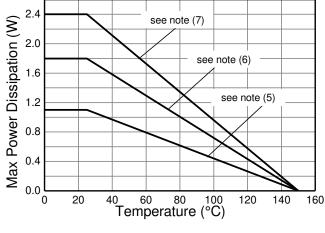
Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5)		1.1	W	
Linear Derating Factor		8.8	mW/°C	
Power Dissipation (Note 6)		1.8	W	
Linear Derating Factor		14.4	mW/°C	
Power Dissipation (Note 7)	PD PD	2.4	W	
Linear Derating Factor		19.2	mW/°C	
Power Dissipation (Note 8)		4.46	W	
Linear Derating Factor		35.7	mW/°C	
Thermal Resistance, Junction to Ambient (Note 5)		117		
Thermal Resistance, Junction to Ambient (Note 6)		68	°C/W	
Thermal Resistance, Junction to Ambient (Note 7)		51	-0/00	
Thermal Resistance, Junction to Ambient (Note 8)		28	1	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

Notes: 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured b) For a device mounted with the exposed conector pad on 15mm x 15mm 102 copurates with air conditions whilst operating in a steady-state.
c) Same as Note (5), except the device is mounted on 25mm x 25mm 2oz copper.
c) Same as Note (5), except the device is mounted on 50mm x 50mm 2oz copper.
c) Same as Note (5), measured at t<5 seconds.</li>



# **Thermal Characteristics and Derating Information**

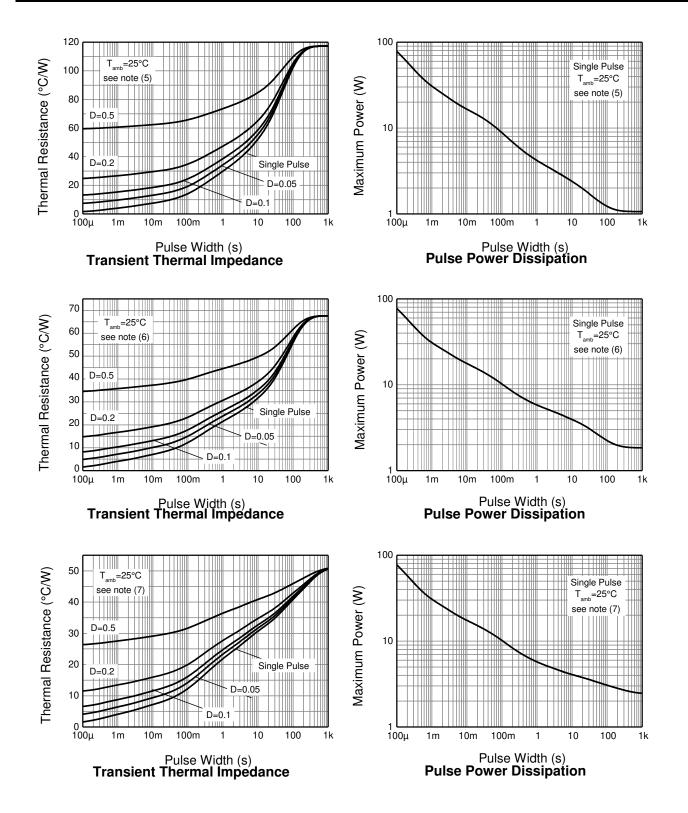




**Derating Curve** 



# **Thermal Characteristics and Derating Information**





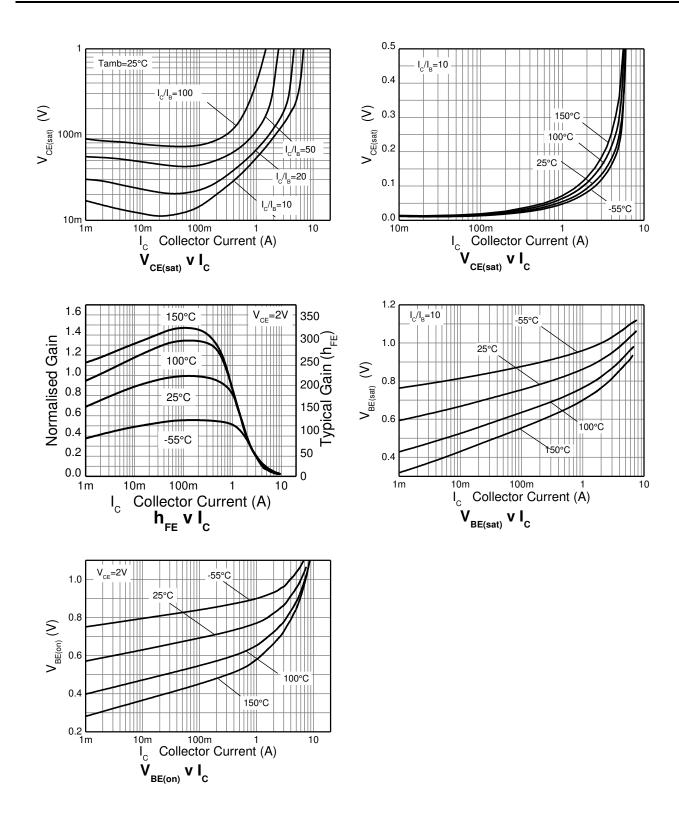
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	150	190	_	V	I <sub>C</sub> = 100μA	
Collector-Emitter Breakdown Voltage (Forward Blocking)	BV <sub>CEX</sub>	150	190	—	v	$I_C = 100 \mu A, R_{BE} \le 1 k\Omega \text{ or} \\ -1V < V_{BE} < 0.25V$	
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	60	80	_	V	I <sub>C</sub> = 10mA	
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8	_	V	I <sub>E</sub> = 100μA	
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV <sub>ECX</sub>	6	8	_	V	$I_E = 100 \mu A, R_{BC} \leq 1 k\Omega \text{ or} \\ -1V < V_{BC} < 0.25V$	
Emitter-Collector Breakdown Voltage (Base Open)	BV <sub>ECO</sub>	6	7	—	V	I <sub>E</sub> = 100μA	
Collector-Base Cutoff Current	I <sub>CBO</sub>	—	1	50 20	nA μA	$V_{CB} = 120V$ $V_{CB} = 120V, T_{amb} = 100^{\circ}C$	
Collector-Emitter Cut-Off Current	I <sub>CEX</sub>	—	—	100	nA	$V_{CE} = 120V, R_{BE} \le 1 k\Omega \text{ or} \\ -1V < V_{BE} < 0.25V$	
Emitter-Base Cut-Off Current	I <sub>EBO</sub>	—	1	50	nA	$V_{EB} = 5.6V$	
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	_	55 70 185 240	70 90 230 305	mV	$\label{eq:lc} \begin{split} I_{C} &= 1A, \ I_{B} = 100 mA \\ I_{C} &= 1A, \ I_{B} = 50 mA \\ I_{C} &= 4A, \ I_{B} = 400 mA \\ I_{C} &= 5A, \ I_{B} = 500 mA \end{split}$	
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(sat)</sub>	—	1020	1100	mV	$I_{C} = 5A, I_{B} = 500mA$	
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(on)</sub>	—	960	1050	mV	$I_C = 5A, V_{CE} = 2V$	
DC Current Gain (Note 9)	h <sub>FE</sub>	100 90 45 —	200 180 90 20	300 — — —	_	$\label{eq:lc} \begin{array}{l} I_{C} = 10mA,  V_{CE} = 2V \\ I_{C} = 1A,  V_{CE} = 2V \\ I_{C} = 2A,  V_{CE} = 2V \\ I_{C} = 5A,  V_{CE} = 5V \end{array}$	
Transitional frequency	f⊤	_	185	_	MHz	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 5V f=100MHz	
Output capacitance	Cobo	_	11.5	20	pF	V <sub>CB</sub> = 10V, f=1MHz	
Delay Time	t <sub>d</sub>	—	16	—	ns		
Rise Time	t <sub>r</sub>	—	15	—	ns	$V_{CC} = 10V, I_{CC} = 500mA$	
Storage Time	ts	—	509	—	ns	$I_{B1} = -I_{B2} = 50 \text{mA}$	
Fall Time	t <sub>f</sub>		57		ns		

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%



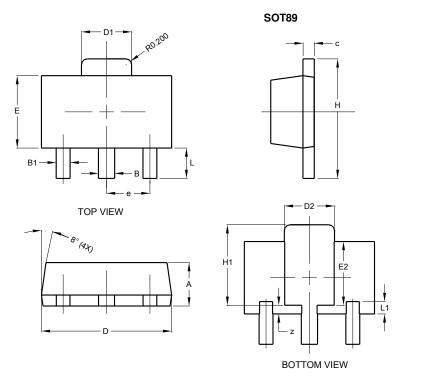
# Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)





# **Package Outline Dimensions**

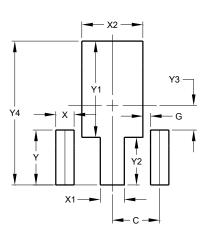
Please see http://www.diodes.com/package-outlines.html for the latest version.



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SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
E	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
z	0.20	0.40	0.30		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.500
G	0.244
Х	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

SOT89



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